NSN 5961-01-508-7329

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-508-7329 **Inclosure Material:** Plastic **Overall Length:** Between 0.610 inches and 0.628 inches **Overall Height:** Between 0.165 inches and 0.200 inches **Overall Width:** Between 0.480 inches and 0.500 inches **End Application:** Air combat maneuvering instrumentation (acmi) **Mounting Facility Quantity:** 2 **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 1200.0 repetitive peak reverse voltage and 1200.0 working peak reverse voltage **Current Rating Per Characteristic:** 100.00 amperes forward current, average and 200.00 amperes source cutoff current outside diameter **Power Rating Per Characteristic:** 300.0 watts small-signal input power, common-emitter peak **Product Name:** 100a, 1200v hyperfast diode **Terminal Type And Quantity:** 2 unthreaded hole Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: